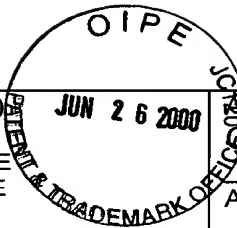


FORM PTO-1449 (SUBSTITUTE)

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICEINFORMATION DISCLOSURE
STATEMENT BY APPLICANT
(37 CFR 1.98(b))Attorney Docket No.:
GR 96 P 8091 PSerial No.
09/283,907

Applicant

Michael Kelly et al.

Filing Date
April 1, 1999Group Art Unit
2812

U.S. PATENT DOCUMENTS

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
	A	6,071,795	06/06/00	Cheung et al.			
	B						
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FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES NO
	J	0 987 741 A1	03/22/00	Europe			X
	K						
	L						
	M						
	N						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

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	P	

EXAMINER

DATE CONSIDERED

September 25, 2001

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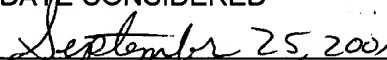
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

	O	C.R. Miskys et al.: "MOCVD-Epitaxy on Free-Standing HVPE-GaN Substrates", phys. stat. sol. (a) 176, 443 (1999), pp. 443-446
	P	L. Tsakalakos et al.: "Epitaxial ferroelectric (Pb,La)(Zr,Ti)O ₃ thin films on stainless steel by excimer laser liftoff", Applied Physics letters, Volume 76, number 2, January 10, 2000, pp. 227-229

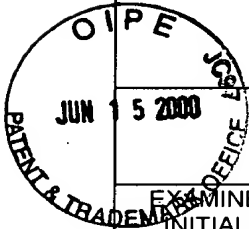
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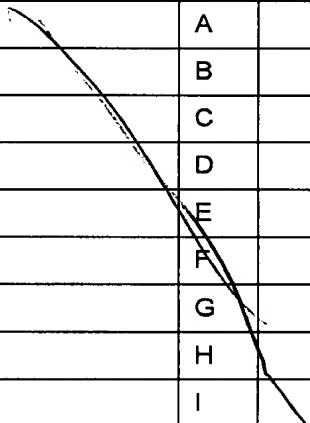
FORM PTO-1449 (SUBSTITUTE) U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICANT (37 CFR 1.98(b))				Attorney Docket No.: GR 96 P 8091 Appl. No. 09/283,907 Applicant MICHAEL KELLY ET AL. Filing Date APRIL 1, 1999 Group Art Unit			
EXAMINER INITIALS	PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE	
A	4,448,636	05/84	Baber				
B	4,883,561	11/89	Gmitter et al.				
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FOREIGN PATENT DOCUMENT							
	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES NO	
J	3508469A1	09/86	Germany			X	
K	0718885A2	06/96	Europe			X	
L							
M							
N							
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)							
1	"Optical patterning of GaN films", M.K. Kelly et al., Appl. Phys. Lett. 69 (12), September 16, 1996, pp. 1749-1751						
2	"Extreme selectivity in the lift-off of epitaxial GaAs films", Eli Yablonovitch et al., Appl. Phys. Lett. 51 (26), December 28, 1987, pp. 2222-2224						
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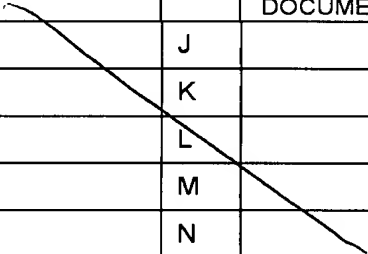
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OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)							
	3	"On the Thermal Decomposition of GaN in Vacuum", R. Groh et al., pp. 353-357					
	4	"Few Characteristics of Epitaxial GaN-Etching and Thermal Decomposition", Yasua Morimoto, J. Electrochem. Soc.: Solid-State Science and Technology, October 1974, pp. 1383-1384					
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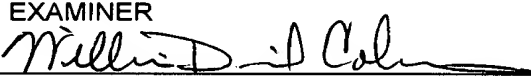
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FORM PTO-1449 (SUBSTITUTE)	Attorney Docket No.: GR 96 P 8091	Appl. No. 09/283,907
U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	Applicant MICHAEL KELLY ET AL.	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (37 CFR 1.98(b))	Filing Date APRIL 1, 1999	Group Art Unit

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OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)		
	5	"Photoassisted dry etching of GaN", R.T. Leonard et al., Appl. Phys. Lett. 68, February 5, 1996, pp. 794-796
	6	"Laser-Induced Dry Lift-off Process", Young-Feng Lu et al., Jpn. J. Appl. Phys. Vol. 34, 1995, pp. 1669-1670
EXAMINER 		DATE CONSIDERED September 25, 2001
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EXAMINER INITIALS	A	PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE

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DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES	TRANSL. NO	

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)		
	1	"Excimer-Laser Removal of SiO ₂ Patterns from GaAs Substrates", Young-Feng Lu et al., Jpn. J. Appl. Phys., Vol. 33, 1994, pp. 324-327

EXAMINER 	DATE CONSIDERED <u>September 25, 2001</u>
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